## WHAT IS CLAIMED IS:

1. A liquid crystal display device, comprising:

at least two storage capacitors disposed between a gate line and a capacitor electrode, said gate line being connected, via a contact hole passing through said at least two storage capacitors, to the capacitor electrode.

- 2. The liquid crystal display device as claimed in claim 1, wherein the capacitor electrode is made from a transparent conductive material selected from the group consisting of indium-tin-oxide, indium-zinc-oxide and indium-tin-zinc-oxide.
- 3. The liquid crystal display device as claimed in claim 1, further comprising:
- a gate insulating film provided on a substrate;
- a storage electrode provided on the gate insulating film; and
- a protective layer provided between the storage electrode and the capacitor electrode.
- 4. The liquid crystal display device as claimed in claim 3, wherein the storage capacitor includes:
- a first storage capacitor provided between the storage electrode and the gate line with the intervening gate insulating film; and

a second storage capacitor provided between the storage electrode and the capacitor electrode with the intervening protective layer.

- 5. The liquid crystal display device as claimed in claim 4, wherein the first storage capacitor is connected to the second storage capacitor in parallel.
- 6. The liquid crystal display device as claimed in claim 4, wherein the contact hole is at least two holes spaced to each other at a length larger than the width of the storage electrode.
- 7. The liquid crystal display device as claimed in claim 6, wherein the capacitor electrode has a length larger than the storage electrode.
- 8. The liquid crystal display device as claimed in claim 3, further comprising:
  - a gate electrode connected to the gate line;
  - source and drain electrodes provided on the gate insulating film; and
- a pixel electrode provided on the protective layer to be electrically connected to the drain electrode.

- 9. The liquid crystal display device as claimed in claim 3, wherein the pixel electrode electrically contacts the storage electrode through said contact hole passing through the protective layer.
- 10. The liquid crystal display device as claimed in claim 8, wherein the gate insulating film has a thickness of about 4000Å.
- 11. The liquid crystal display device as claimed in claim 8, wherein the protective layer has a thickness of about 2000Å.
- 12. A method of fabricating a liquid crystal display device, comprising the steps of:

forming a gate line on a substrate;

forming a gate insulating film on the substrate;

forming a storage electrode on the gate insulating film;

forming a protective layer on the gate insulating film;

defining at least two contact holes to expose the gate line; and

forming a capacitor electrode electrically contacting the gate line on the protective layer.

13. The method as claimed in claim 12, wherein the capacitor electrode is made from a transparent conductive material selected from the group consisting of indium-tin-oxide, indium-zinc-oxide and indium-tin-

zinc-oxide.

- 14. The method as claimed in claim 12, wherein the said least two contact holes are spaced to each other at a length larger than the width of the storage electrode.
- 15. The method as claimed in claim 14, wherein the capacitor electrode has a length larger than the storage electrode.
- 16. The method as claimed in claim 12, further comprising the steps of:

forming a gate electrode connected to the gate line on the substrate; forming a semiconductor layer on the gate insulating film; forming source and drain electrodes on the semiconductor layer; and forming a pixel electrode on the protective layer.

- 17. The method as claimed in claim 16, wherein the pixel electrode electrically contacts the storage electrode through said contact hole passing through the protective layer.
- 18. The method as claimed in claim 16, wherein the gate insulating film has a thickness of about 4000Å.

19. The method as claimed in claim 16, wherein the protective layer has a thickness of about 2000Å.